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```
% Student Name: Patrobas Adewumi
% Student Number: 100963608
% ELEC 4700: The Physics and Modeling of Advanced Devices and Technologies
% Assignment#1: Monte-Carlo Modeling of Electron Transport

clearvars
clearvars -GLOBAL
close all

global C
global X Y
    C.q_0 = 1.60217653e-19;           % electron charge
    C.hb = 1.054571596e-34;          % Dirac constant
    C.h = C.hb * 2 * pi;              % Planck constant
    C.m_0 = 9.10938215e-31;           % electron rest mass
    C.kb = 1.3806504e-23;             % Boltzmann constant
    C.eps_0 = 8.854187817e-12;        % vacuum permittivity
    C.mu_0 = 1.2566370614e-6;         % vacuum permeability
    C.c = 299792458;                  % speed of light
    C.g = 9.80665;                    % metres (32.1740 ft) per s^2

mn = 0.26*C.m_0;                     % effective masss of electron
Temp = 300;                           % In kelvin
runTime = 10000;                       % run time in timesteps
Tmn = 0.2e-12;                         % mean time between collisions
sizeX = 200e-9;                        % normal size of the region in x dir (length)
sizeY = 100e-9;                        % normal size of the region in y dir (width)

%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%% Electron Modelling %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
```

Modeling the electrons in the silicon as particles with the effective %

```
%%% mass above using a simplistic Monte-Carlo model %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
```

Thermal Velocity

%%

Thermal velocity is the velocity that a particle in a system %%%%%%%%%

would have if its kinetic energy were equal to the average energy %%%%%

of all the particles of the system.

```
Vth = sqrt(2*C.kb*Temp/mn);
##### Setting up the semiconductor region given #####

size = 1000;
dispSize = 10;
##### Assigning each particle a random location in the x?y plane #####
##### within the region defined by the extent of the Silicon #####
X = rand(2,size);
Y = rand(2,size);

Pos_X(1,:)= X(1,:)*sizeX;
Pos_Y(1,:)= Y(1,:)*sizeY;
colour = rand(1,dispSize);

##### Assigning each particle with the fixed velocity given by vth #####
##### but give each one a random direction #####
angle(1,:) = X(2,:)*2*pi;

##### Collisions with Mean Free Path (MFP) #####
##### Normal distribution of velocity #####

sigma = sqrt(C.kb*Temp/mn)/4;
mu = Vth;
MB_dist = makedist('Normal',mu,sigma);
Vel = random(MB_dist,1,size);
Vel_X(1,:) = Vel(1,:).* cos(angle(1,:));
Vel_Y(1,:) = Vel(1,:).* sin(angle(1,:));

Vel_sum = sum(Vel)/size;
##### Histogram of velocity #####
##### Set timestep of function and variable change #####
spacStep = 0.01*sizeY;
dt = spacStep/Vth;
steps = 1000;

Vel_X(1,:) = Vel_X(1,:)*dt;
Vel_Y(1,:) = Vel_Y(1,:)*dt;
```

## Part 2

```

Vel_Y(ScatCheck) = Vel(ScatCheck).*sin(angle(ScatCheck)).*dt;
MFP_count(~ScatCheck) = MFP_count(~ScatCheck)+ spacStep;
MFP_count(ScatCheck) = 0;

CheckRHSPos_X = Pos_X + Vel_X > 2e-7;
Pos_X(CheckRHSPos_X) = Pos_X(CheckRHSPos_X)+ Vel_X(CheckRHSPos_X)- sizeX;
CheckLHSPos_X = Pos_X + Vel_X < 0;
Pos_X(CheckLHSPos_X) = Pos_X(CheckLHSPos_X) + Vel_X(CheckLHSPos_X)+ sizeX;

leftover = ~(CheckRHSPos_X | CheckLHSPos_X);
Pos_X(leftover) = Pos_X(leftover) + Vel_X(leftover);

%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%% Y boundary reflection %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
checkPos_Y = (Pos_Y + Vel_Y > 1e-7 | Pos_Y + Vel_Y < 0);
Vel_Y(checkPos_Y) = Vel_Y(checkPos_Y).*(-1);
Pos_Y(1,:) = Pos_Y(1,:) + Vel_Y(1,:);

%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%% Semiconductor Temperature calculations %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
mean_Vel = sum(Vel)/size;
calcTemp(1,i) = mn*(mean_Vel)^2/(2*C.kb);

%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%% Mean Free Path calculation %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
MFP = sum(MFP_count)/size;
Tmn_avg = MFP/mean_Vel;

%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%% Setting up PlotsP %%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%%
prev_Pos_X(i,:) = Pos_X(1,:);
prev_Pos_Y(i,:) = Pos_Y(1,:);

```

end

figure(3)

for j = 1:1:dispSize

```

plot(prev_Pos_X(:,j),prev_Pos_Y(:,j),'color',[colour(1,j) 0 j/dispSize])
title('Particle Trajectories: with Scattering')
xlabel('Length of semiconductor region')
ylabel('width of semiconductor region')
xlim([0 sizeX])
ylim([0 sizeY])
drawnow
hold on

```

end

figure(4)

```

plot(linspace(1,size,size),calcTemp);
title('Temperature plot: Calculated')
xlabel('Time step')
ylabel('Temperature (K)')
ylim([270 330])

```

figure(5)

```

title('Velocity Histogram')
hist(Vel)

```

display('The Mean Free Path (MFP) of electrons using an exponential scattering probability and found to be')

```

display(MFP)
display('The Mean Time Between Collisions is is found to be ')
display(Tmn_avg)

```

The Mean Free Path (MFP) of electrons using an exponential scattering probability and found to be

MFP =

3.5142e-08

The Mean Time Between Collisions is is found to be

Tmn\_avg =

1.8741e-13





